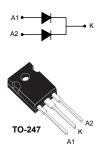


STPS40H100CW

Datasheet

100 V power Schottky rectifier



Features

- Negligible switching losses
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- Low thermal resistance
- Avalanche specification
- ECOPACK[®]2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Desktop power supply

Description

This dual diode common cathode Schottky rectifier is suited for switch mode power supply and high frequency DC to DC converters.

Packaged in TO-247, the STPS40H100CW is optimized for use in high frequency inverters.

Product status link				
STPS40H100CW				
Product summary				
Symbol Value				
I _{F(AV)}	2 x 20 A			
V_{RRM} 100 V				
Т ј 175 °С				
V _F (typ.)	0.58 V			

1 Characteristics

Table 1. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			100	V
I _{F(RMS)}	Forward rms current			30	Α
		T _c = 160 °C	Per diode	20	
I _{F(AV)}	Average forward current, δ = 0.5 square wave	$are wave = 1_c = 100 C$	Per device	40	A
I _{FSM}	Surge non repetitive forward current t _p = 10 ms sinusoidal			300	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 10 \ \mu s, T_j = 125 \ ^{\circ}C$			1900	W
T _{stg}	Storage temperature range			-65 to +175	°C
Tj	Maximum operating junction temperature range ⁽¹⁾			+175	°C

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter		Max. value	Unit
R _{th(j-c)}	Junction to case	Per diode	0.9	°C/W
		Total	0.50	
R _{th(c)}	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously :

 ΔT_j (diode 1) = P(diode1) x R_{th(j-c)}(per diode) + P(diode 2) x R_{th(c)}

For more information, please refer to the following application note:

AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
		T _j = 25 °C	V _R = V _{RRM}	-		10	μA
I _R ⁽¹⁾	Reverse leakage current	T _j = 125 °C		-	5	15	mA
V _F ⁽²⁾ Forward voltag		T _j = 25 °C	I _F = 20 A	-		0.73	V
	Forward voltage drag	T _j = 125 °C		-	0.58	0.61	
	Porward voltage drop	T _j = 25 °C	I _F = 40 A	-		0.85	
		T _j = 125 °C		-	0.67	0.72	

1. Pulse test: $t_p = 5 ms, \delta < 2\%$

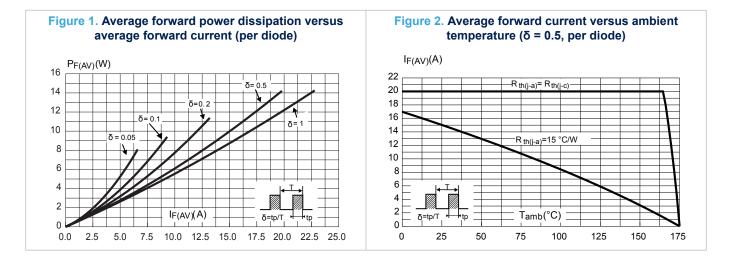
2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

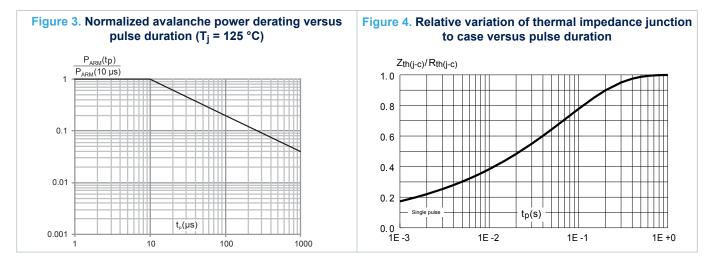
To evaluate the conduction losses, use the following equation: P = 0.5 x $I_{F(AV)}$ + 0.0055 x $I_{F}^{2}(RMS)$ For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

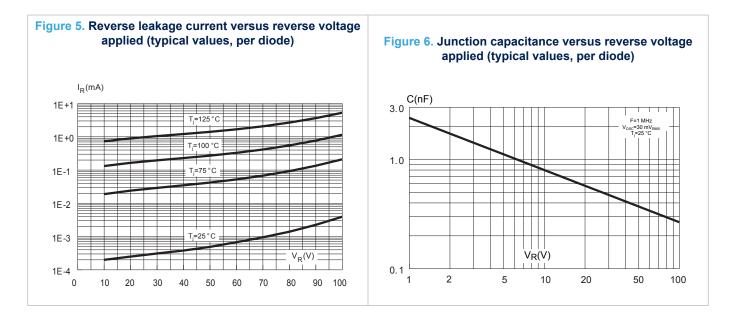


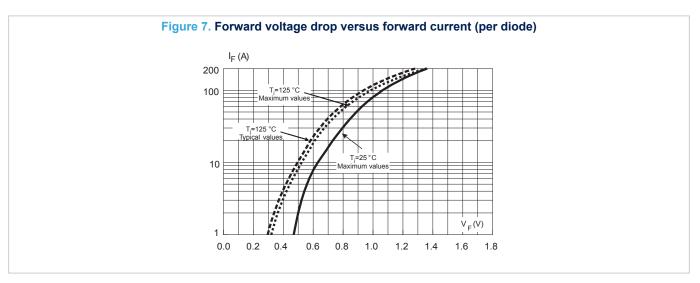
1.1 Characteristics (curves)











2 Package information

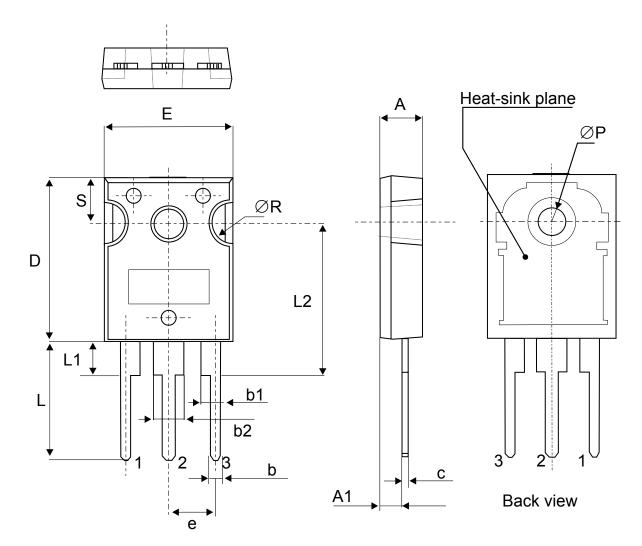
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In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 TO-247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1.0 N·m





	Dimensions						
Ref.	Millimeters			Inches (for reference only)			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.85		5.15	0.191		0.203	
A1	2.20		2.60	0.086		0.102	
b	1.00		1.40	0.039		0.055	
b1	2.00		2.40	0.078		0.094	
b2	3.00		3.40	0.118		0.133	
С	0.40		0.80	0.015		0.031	
D	19.85		20.15	0.781		0.793	
E	15.45		15.75	0.608		0.620	
е	5.30	5.45	5.60	0.209	0.215	0.220	
L	14.20		14.80	0.559		0.582	
L1	3.70		4.30	0.145		0.169	
L2		18.50			0.728		
ØP	3.55		3.65	0.139		0.143	
ØR	4.50		5.50	0.177		0.217	
S	5.30	5.50	5.70	0.209	0.216	0.224	

Table 4. TO-247 package mechanical data



3 Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40H100CW	STPS40H100CW	TO-247	4.36 g	30	Tube

Revision history

Table 6. Document revision history

Date	Version	Changes
Jul-2003	4D	Previous release.
16-Jan-2013	5	Updated package graphic to clarify lead length.
03-Jul-2018	6	Updated Table 1. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125$ °C).



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